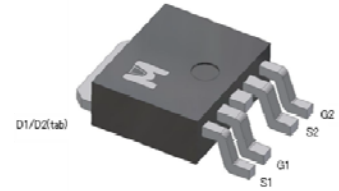
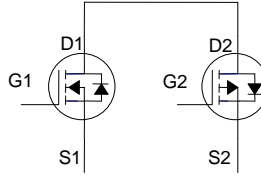


N & P-Channel Logic Level Enhancement Mode Field Effect Transistor

Product Summary:

	N-CH	P-CH
BV_{DSS}	40V	-40V
$R_{DS(on) (MAX.)}$	15m Ω	30m Ω
I_D	9A	-7A



Pb-Free Lead Plating & Halogen Free



ABSOLUTE MAXIMUM RATINGS ($T_c = 25^\circ\text{C}$ Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS		UNIT
Gate-Source Voltage		V_{GS}	N-CH	P-CH	V
			± 20	± 20	
Continuous Drain Current	$T_c = 25^\circ\text{C}$	I_D	9	-7	A
	$T_c = 70^\circ\text{C}$		7	-5.5	
Pulsed Drain Current ¹		I_{DM}	36	-28	
Power Dissipation	$T_c = 25^\circ\text{C}$	P_D	21		W
	$T_c = 70^\circ\text{C}$		13		
Operating Junction & Storage Temperature Range		T_{j}, T_{stg}	-55 to 150		$^\circ\text{C}$

THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNIT
Junction-to-Case	$R_{\theta JC}$		6	$^\circ\text{C} / \text{W}$
Junction-to-Ambient ³	$R_{\theta JA}$		42	

¹Pulse width limited by maximum junction temperature.

²Duty cycle $\leq 1\%$



ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, Unless Otherwise Noted)

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT	
			MIN	TYP	MAX		
STATIC							
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$ $V_{GS} = 0V, I_D = -250\mu A$	N-CH	40		V	
			P-CH	-40			
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$ $V_{DS} = V_{GS}, I_D = -250\mu A$	N-CH	1.0	2.0	3.0	
			P-CH	-1.0	-2.0	-3.0	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 20V$ $V_{DS} = 0V, V_{GS} = \pm 20V$	N-CH			± 100	nA
			P-CH			± 100	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 32V, V_{GS} = 0V$ $V_{DS} = -32V, V_{GS} = 0V$ $V_{DS} = 30V, V_{GS} = 0V, T_J = 125\text{ }^\circ\text{C}$ $V_{DS} = -30V, V_{GS} = 0V, T_J = 125\text{ }^\circ\text{C}$	N-CH			1	μA
			P-CH			-1	
			N-CH			25	
			P-CH			-25	
On-State Drain Current ¹	$I_{D(ON)}$	$V_{DS} = 5V, V_{GS} = 10V$ $V_{DS} = -5V, V_{GS} = -10V$	N-CH	9			A
			P-CH	-7			
Drain-Source On-State Resistance ¹	$R_{DS(ON)}$	$V_{GS} = 10V, I_D = 9A$ $V_{GS} = -10V, I_D = -7A$ $V_{GS} = 7V, I_D = 7A$ $V_{GS} = -7V, I_D = -5A$	N-CH		13	15	m Ω
			P-CH		24	30	
			N-CH		16	20	
			P-CH		32	40	
Forward Transconductance ¹	g_{fs}	$V_{DS} = 5V, I_D = 9A$ $V_{DS} = -5V, I_D = -7A$	N-CH		25		S
			P-CH		20		
DYNAMIC							
Input Capacitance	C_{iss}	N-CH $V_{GS} = 0V, V_{DS} = 20V, f = 1MHz$ P-CH $V_{GS} = 0V, V_{DS} = -20V, f = 1MHz$	N-CH		1090		pF
Output Capacitance	C_{oss}		P-CH		1518		
			N-CH		133		
Reverse Transfer Capacitance	C_{rss}		P-CH		207		
			N-CH		106		
			P-CH		161		



Total Gate Charge ^{1,2}	Q_g	N-CH $V_{DS} = 20V, V_{GS} = 10V,$ $I_D = 9A$ P-CH $V_{DS} = -20V, V_{GS} = -10V,$ $I_D = -7A$	N-CH		24	nC	
Gate-Source Charge ^{1,2}	Q_{gs}		P-CH		25		
Gate-Drain Charge ^{1,2}	Q_{gd}		N-CH		3		
			P-CH		3.7		
Turn-On Delay Time ^{1,2}	$t_{d(on)}$		N-CH		10		nS
			P-CH		13		
Rise Time ^{1,2}	t_r	$I_D = 1A, V_{GS} = 10V, R_{GS} = 6\Omega$	N-CH		11		
			P-CH		25		
Turn-Off Delay Time ^{1,2}	$t_{d(off)}$		P-CH $V_{DS} = -20V,$ $I_D = -1A, V_{GS} = -10V, R_{GS} = 6\Omega$	N-CH		16	
				P-CH		40	
Fall Time ^{1,2}	t_f	N-CH			15		
		P-CH			32		
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_c = 25^\circ C$)							
Continuous Current	I_S		N-CH		9	A	
			P-CH		-7		
Pulsed Current ³	I_{SM}		N-CH		20		
			P-CH		-20		
Forward Voltage ¹	V_{SD}		$I_F = I_S, V_{GS} = 0V$	N-CH		1.3	V
				P-CH		-1.3	

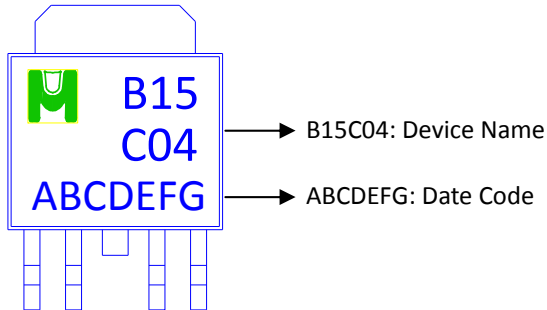
¹Pulse test : Pulse Width $\leq 300 \mu\text{sec}$, Duty Cycle $\leq 2\%$.

²Independent of operating temperature.

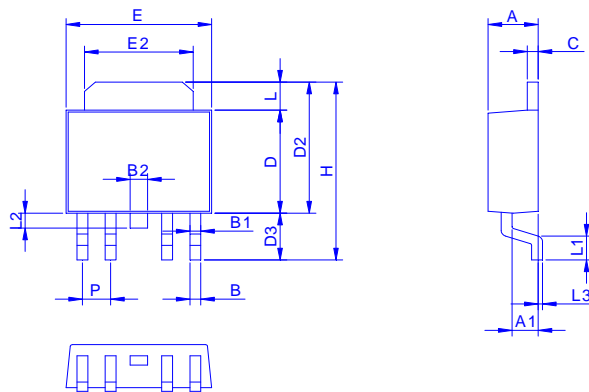
³Pulse width limited by maximum junction temperature.

Ordering & Marking Information:

Device Name: EMB15C04A for DPAK (TO-252)

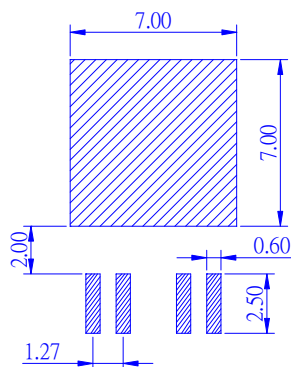


Outline Drawing



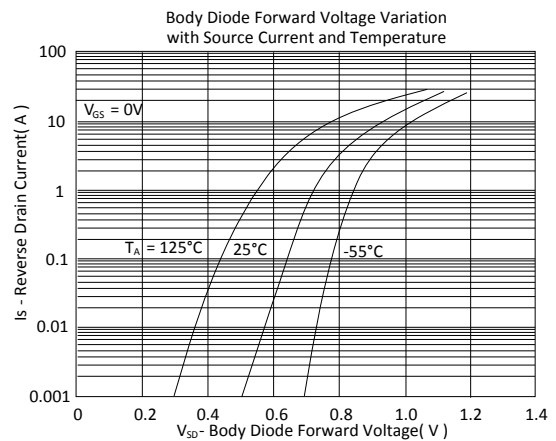
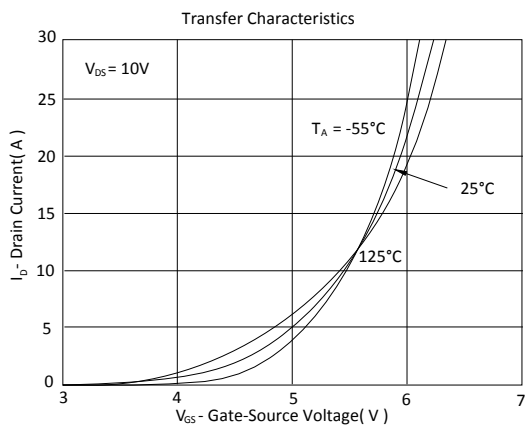
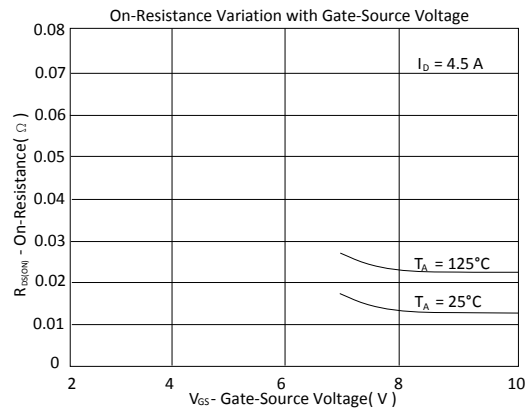
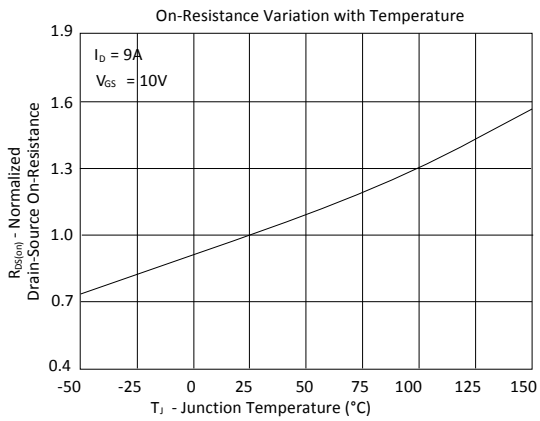
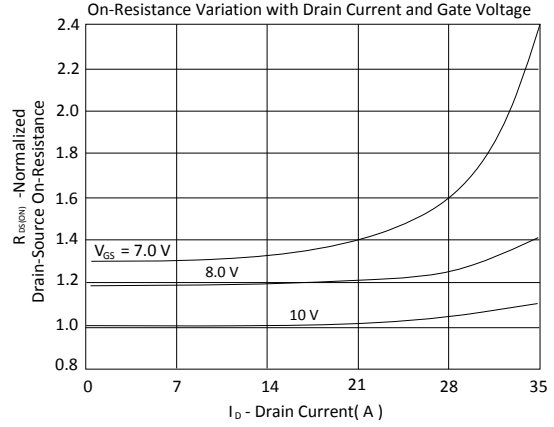
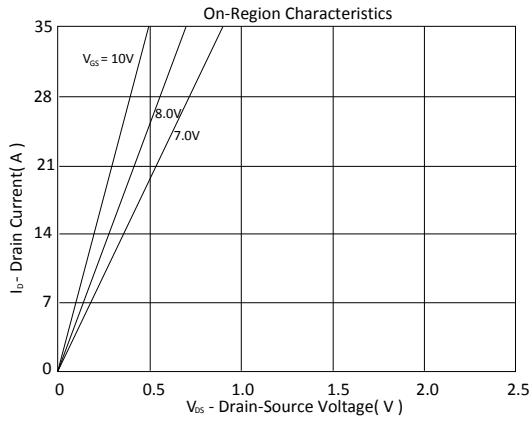
Dimension in mm

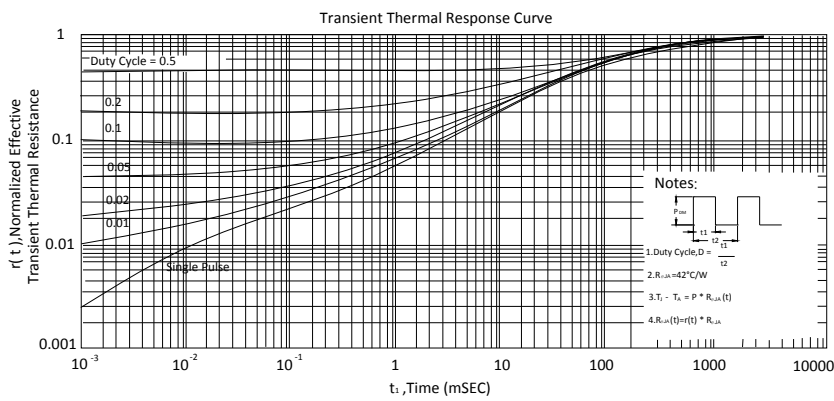
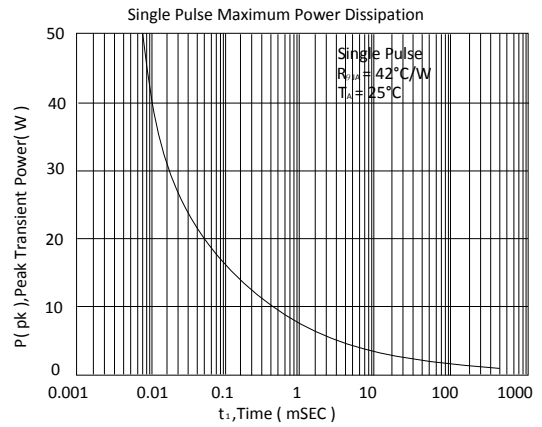
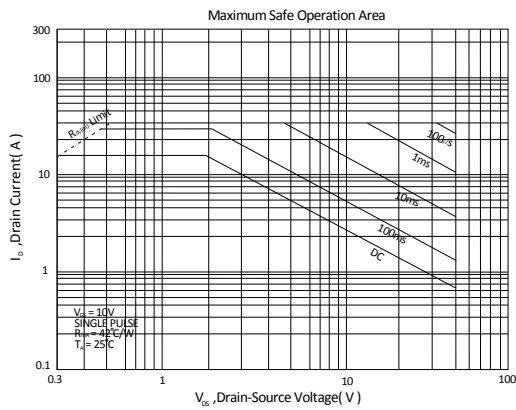
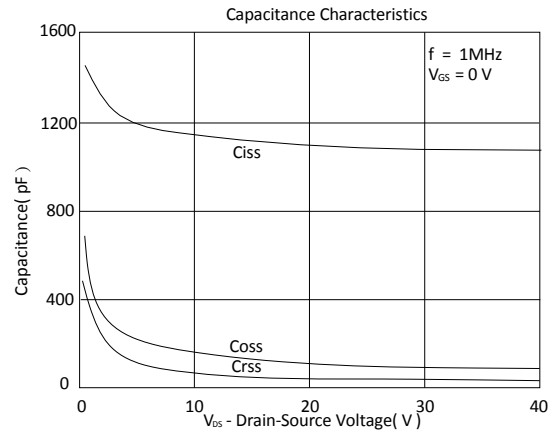
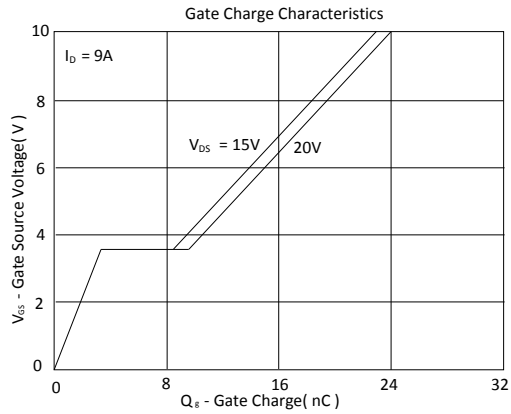
Dimension	A	A1	B	B1	B2	C	D	D2	D3	E	E2	H	L	L1	L2	L3	P
Min.	2.10	1.10	0.30	0.55	0.40	0.40	5.30	6.70	2.20	6.30	4.80	9.20	1.30	0.90	0.50	0.00	1.17
Max.	2.50	1.30	0.70	0.75	0.80	0.60	5.70	7.30	3.00	6.70	5.45	10.15	1.70	1.50	1.10	0.30	1.37





N-Channel







P-Channel

